# 2 A, 40 V Schottky Barrier Diode

These Schottky barrier diodes are optimized for low forward voltage drop and low leakage current and are offered in a Chip Scale Package (CSP) to reduce board space. The low thermal resistance enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

### Features

- Low Forward Voltage Drop 520 mV (Typ.) @  $I_F = 2 A$
- Low Reverse Current  $35 \mu A$  (Typ.) @ V<sub>R</sub> = 40 V
- 2 A of Continuous Forward Current
- ESD Rating Human Body Model: Class 3B
  - Machine Model: Class C
- High Switching Speed
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Typical Applications**

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

### MAXIMUM RATINGS

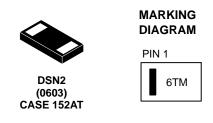
Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	40	V
Forward Current (DC)	١ <sub>F</sub>	2	А
Forward Surge Current (60 Hz @ 1 cycle)	I <sub>FSM</sub>	19	A
Repetitive Peak Forward Current (Pulse Wave = 1 sec, Duty Cycle = 66%)	I <sub>FRM</sub>	3.4	A
ESD Rating: Human Body Model Machine Model	ESD	> 8 > 400	kV V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



# **ON Semiconductor®**

www.onsemi.com



6T = Specific Device Code M = Date Code

#### **PIN CONNECTIONS**

1 0 2 CATHODE ANODE

#### **ORDERING INFORMATION**

	Device	Package	Shipping <sup>†</sup>
NS	R20406NXT5G	DSN2 (Pb-Free)	5000 / Tape & Reel

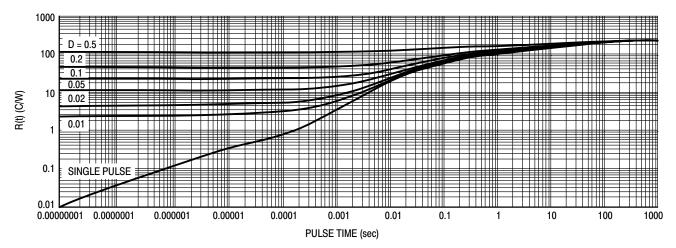
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Thermal Resistance Junction–to–Ambient (Note 1) Total Power Dissipation @ $T_A = 25^{\circ}C$	R <sub>θJA</sub> P <sub>D</sub>			245 510	°C/W mW
Thermal Resistance Junction–to–Ambient (Note 2) Total Power Dissipation @ $T_A = 25^{\circ}C$	R <sub>θJA</sub> P <sub>D</sub>			90 1.4	°C/W W
Storage Temperature Range	T <sub>stg</sub>			-40 to +125	°C
Junction Temperature	TJ			+150	°C

1. Mounted onto a 4 in square FR-4 board 50 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.

2. Mounted onto a 4 in square FR-4 board 650 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.





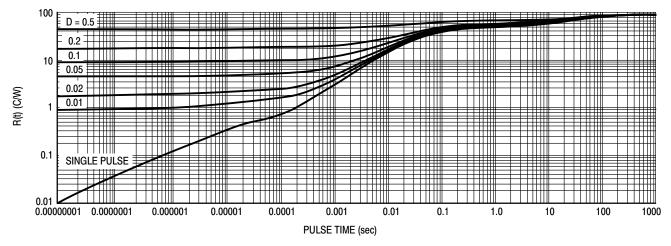
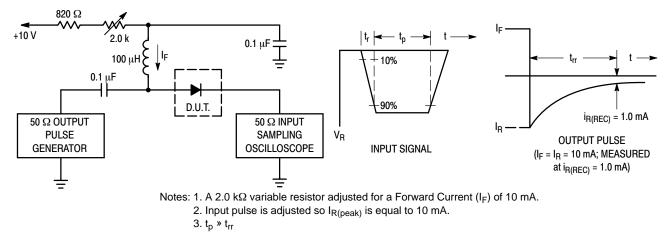


Figure 2. Thermal Response (Note 2)

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Leakage $(V_R = 10 V)$ $(V_R = 40 V)$	I <sub>R</sub>		3 35	15 150	μΑ
Forward Voltage $(I_F = 10 \text{ mA})$ $(I_F = 100 \text{ mA})$ $(I_F = 500 \text{ mA})$ $(I_F = 1 \text{ A})$ $(I_F = 2 \text{ A})$	VF	- - - - -	240 310 380 430 520	280 350 420 470 550	mV
Total Capacitance ( $V_R = 2.0 \text{ V}$ , f = 1.0 MHz)	CT	-	140	_	pF
Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 10 mA, I <sub>R(REC)</sub> = 1.0 mA, Figure 3)	t <sub>rr</sub>	-	53	-	ns
Peak Forward Recovery Voltage (I <sub>F</sub> = 100 mA, $t_r$ = 20 ns, Figure 4)	V <sub>FRM</sub>	-	440	-	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.





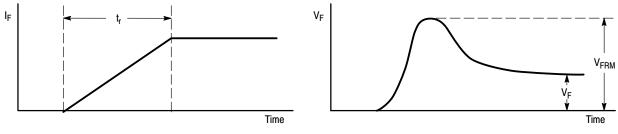
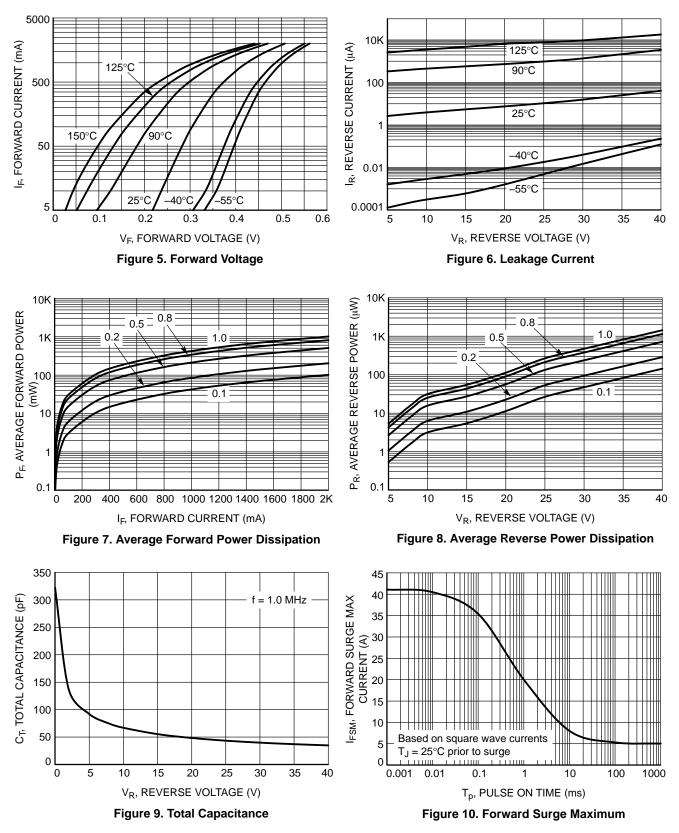
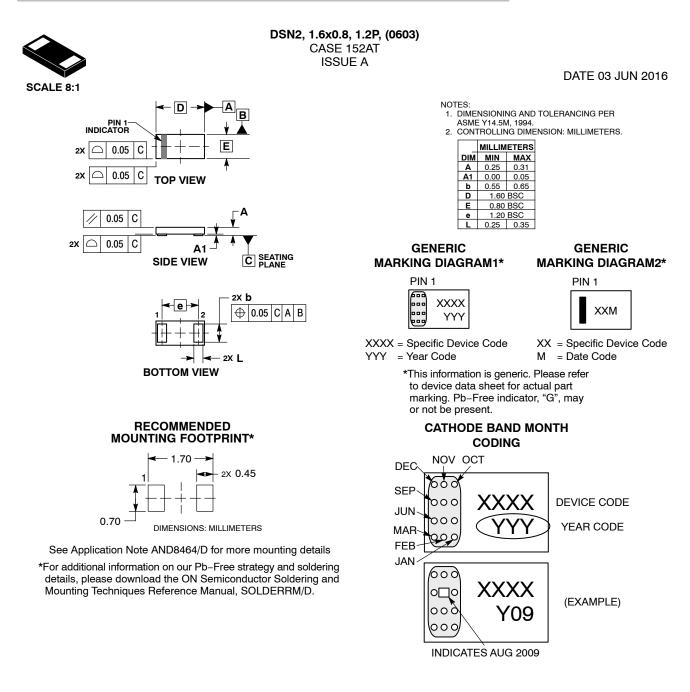


Figure 4. Peak Forward Recover Voltage Definition

### **TYPICAL CHARACTERISTICS**







DOCUMENT NUMBER:	98AON79729F	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	N: DSN2, 1.6X0.8, 1.2P, (0603)		PAGE 1 OF 1		
ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.					

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters, including "Typicals" must be validated for each customer applications by customer's technical experts. onsemi does not cust performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application or autorized for use as a critical component in life support systems or any CDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any divide for indirectly, any claim of personal injury or death associated with such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and is officers, employees, subsidiaries, and expenses, and expenses, and exponses hard snegges that onsemi was negligent regarding the design or unauthorized use ever if such claim alleges that onsemi was negligent regarding the design or manufacture of the part. onsemi is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright have and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### Email Requests to: orderlit@onsemi.com

#### TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

 $\Diamond$